

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 150°C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

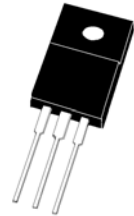


* ESD: 8KV(Min.) Human-Body Model

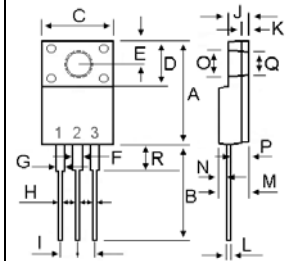
* In compliance with EU RoHs 2002/95/EC directives

SCHOTTKY BARRIER RECTIFIERS

**30 AMPERES
30-60 VOLTS**



ITO-220AB



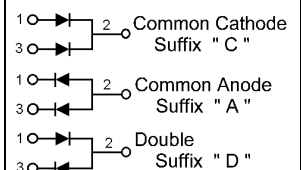
MAXIMUM RATINGS

Characteristic	Symbol	SRF30						Unit
		30	35	40	45	50	60	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	30	35	40	45	50	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	21	25	28	32	35	42	V
Average Rectifier Forward Current (Per diode) Total Device (Rated V_R), $T_C=125^\circ\text{C}$	$I_{F(AV)}$	15 30						A
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz)	I_{FM}	30						A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfwave, single phase, 60Hz)	I_{FSM}	250						A
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +150						°C

DIM	MILLIMETERS	
	MIN	MAX
A	14.90	15.15
B	13.35	13.55
C	10.00	10.10
D	6.55	6.65
E	2.65	2.75
F	1.55	1.65
G	1.15	1.25
H	0.55	0.65
I	2.50	2.60
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
O	3.35	3.45
P	2.65	2.75
Q	3.15	3.25
R	3.60	3.80

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	SRF30						Unit
		30	35	40	45	50	60	
Maximum Instantaneous Forward Voltage ($I_F = 15$ Amp $T_C = 25^\circ\text{C}$) ($I_F = 15$ Amp $T_C = 100^\circ\text{C}$)	V_F	0.55 0.48			0.70 0.61			V
Typical Thermal Resistance junction to case	$R_{\theta j-c}$	3.0						°C/w
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^\circ\text{C}$) (Rated DC Voltage, $T_C = 125^\circ\text{C}$)	I_R	0.5 30						mA



SRF3030 Thru SRF3060

FIG-1 FORWARD CURRENT DERATING CURVE

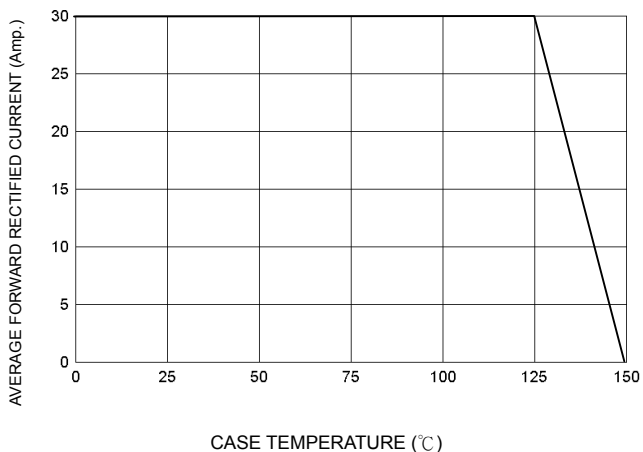


FIG-2 TYPICAL FORWARD CHARACTERISTICS

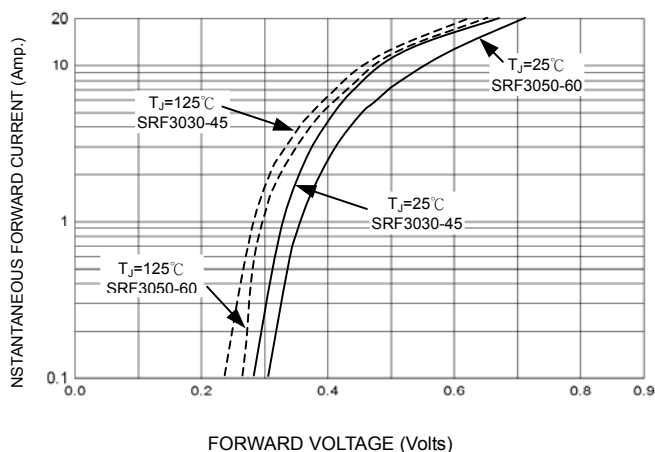


FIG-3 TYPICAL REVERSE CHARACTERISTICS

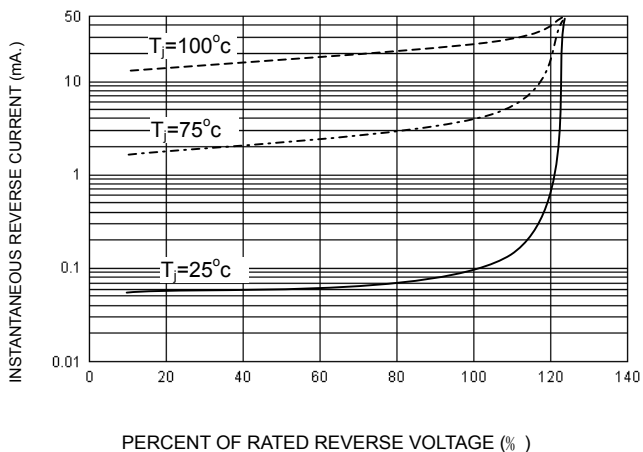


FIG-4 TYPICAL JUNCTION CAPACITANCE

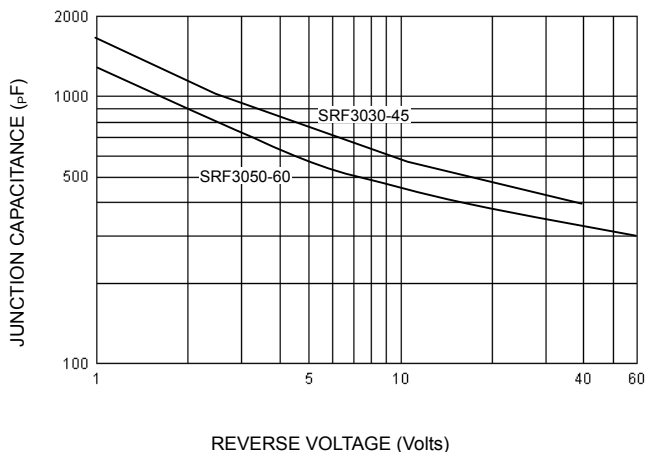


FIG-5 PEAK FORWARD SURGE CURRENT

